## Aniello Pelella

List of Publications by Year in descending order

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932766 940134 19 472 10 16 citations h-index g-index papers 20 20 20 491 docs citations times ranked citing authors all docs

#	Article	IF	Citations
1	Pressureâ€Tunable Ambipolar Conduction and Hysteresis in Thin Palladium Diselenide Field Effect Transistors. Advanced Functional Materials, 2019, 29, 1902483.	7.8	98
2	Field Emission in Ultrathin PdSe <sub>2</sub> Backâ€Gated Transistors. Advanced Electronic Materials, 2020, 6, 2000094.	2.6	66
3	Coexistence of Negative and Positive Photoconductivity in Fewâ€Layer PtSe <sub>2</sub> Fieldâ€Effect Transistors. Advanced Functional Materials, 2021, 31, 2105722.	7.8	53
4	Electron Irradiation of Metal Contacts in Monolayer MoS <sub>2</sub> Field-Effect Transistors. ACS Applied Materials & District Substitution (12), 40532-40540.	4.0	44
5	WS <sub>2</sub> Nanotubes: Electrical Conduction and Field Emission Under Electron Irradiation and Mechanical Stress. Small, 2020, 16, e2002880.	5.2	42
6	Graphene–Silicon Device for Visible and Infrared Photodetection. ACS Applied Materials & Samp; Interfaces, 2021, 13, 47895-47903.	4.0	41
7	Field Emission Characterization of MoS2 Nanoflowers. Nanomaterials, 2019, 9, 717.	1.9	40
8	Gateâ€Controlled Field Emission Current from MoS <sub>2</sub> Nanosheets. Advanced Electronic Materials, 2021, 7, 2000838.	2.6	37
9	Field Emission Characteristics of InSb Patterned Nanowires. Advanced Electronic Materials, 2020, 6, 2000402.	2.6	18
10	Memory effects in black phosphorus field effect transistors. 2D Materials, 2022, 9, 015028.	2.0	17
11	Air Pressure, Gas Exposure and Electron Beam Irradiation of 2D Transition Metal Dichalcogenides. Applied Sciences (Switzerland), 2020, 10, 5840.	1.3	5
12	SnO <sub>2</sub> Nanofibers Network for Cold Cathode Applications in Vacuum Nanoelectronics. Advanced Electronic Materials, 2022, 8, .	2.6	5
13	Electrical Conduction and Photoconduction in PtSe2 Ultrathin Films. Materials Proceedings, 2020, 4, .	0.2	2
14	2D transition metal dichalcogenides nanosheets as gate modulated cold electron emitters., 2021,,.		1
15	Temperature Dependence of Germanium Arsenide Field-Effect Transistors Electrical Properties. Materials Proceedings, 2021, 4, 26.	0.2	1
16	Sensors Based on Multiwalled Carbon Nanotubes. Materials Proceedings, 2021, 4, 59.	0.2	1
17	Modification of contacts and channel properties in two-dimensional field-effect transistors by $10\text{keV}$ electron beam irradiation. , $2021,$ , .		0
18	Molybdenum Disulfide Field Effect Transistors under Electron Beam Irradiation and External Electric Fields. Materials Proceedings, 2021, 4, 25.	0.2	0

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#	Article	IF	CITATIONS
19	Direct Contacting of 2D Nanosheets by Metallic Nanoprobes. Materials Proceedings, 2020, 4, .	0.2	0